

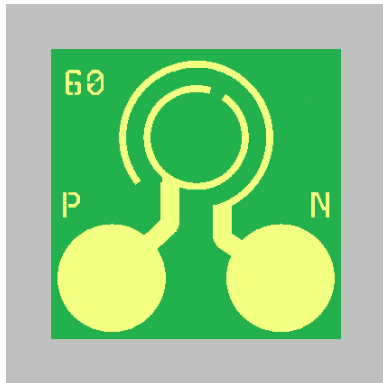
14Gbps GaAs PIN Photodiode & Array

P/N: DO433_60um_G14 (_1x4, _1x8, _1x12 for arrays)



Known Good Die

DATASHEET



Introduction

The DO433_60um_G14 products are high performance front side illuminated GaAs PIN photodiode arrays that feature low capacitance, high responsivity, and extremely low dark current with proven excellent reliability. These products have a 60µm detection window. Primarily designed to meet the performance requirements for 14Gbps short range optical data communication, the product chip dimensions are specially tailored to meet the packaging requirement for up to 14Gbps Active Optical Cable (AOC) receiver operating at 850nm with multimode fibers. Singlets, 1x4, 1x8 and 1x12 array are all provided.

Key Features

- Mesa structure with 60µm optical detection window
- Excellent low dark current and capacitance
- -40C to 85C operation range
- Suitable for non-hermetic package
- Customization for 1x4, 1x8 and 1x12 array configuration
- Different pad sequence available
- Highly robust 4" GaAs IC wafer fab with fast cycle-time
- Deliverable with 100% testing and inspection
- RoHS compliant

Applications

- 14Gbps AOC (Active Optical Cable) receiver at 850nm
- Singlets, 1x4, 1x8, 1x12
- Infiniband
- SONET/SDH

SPECIFICATIONS (T=25C)

	Conditions	Min.	Typical	Max.	Unit	Notes
Bandwidth	-3V	-	12	-	GHz	
Wavelength range		760	850	860	nm	
Capacitance	-3 V	-	0.17	0.20	pF	
Responsivity	@850 nm	0.5	-	0.6	A/W	
Dark current	-3V	-	<0.1	0.3	nA	
Reverse Breakdown	-20V	-	-	1	µA	

ABSOLUTE MAXIMUM RATING

Parameter	Rating
Operating Temperature	-40C to 85C
Storage Temperature	-55C to 125C
Forward Current	10mA

Global Communication Semiconductors, LLC

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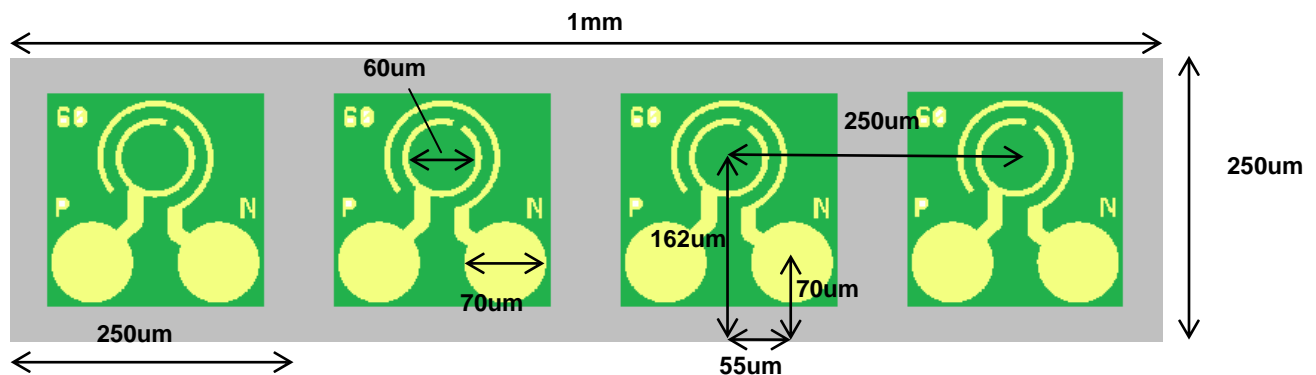
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www.gcsincorp.com

DIMENSIONS

	Conditions	Min.	Typical	Max.	Unit	Notes
Detection window		-	60	-	μm	
Die pitch		-	250	-	um	
Bonding pad diameter		-	70	-	μm	for both p- and n- pads
Die height		140	150	160	μm	
Die width		240	250	260	μm	
Die length			250		um	For Singlet
			1		mm	For 1x4 Array
			2		mm	For 1x8 Array
			3		mm	For 1x12 Array

BONDING PAD CONFIGURATION



P/N: DO395_40um_Q8

Attention: Avoid ESD; the device may be permanently damaged.

About GCS:

GCS is a world-class semiconductor manufacturer specializing in advanced photodiode technologies. We provide advanced GaAs and InGaAs photodiodes of varying data rate and application to multiple top tier optical transceiver customers throughout the world. With over 15 years' experience and over 150 million units delivered, our state of the art manufacturing facility has the capacity to produce 2,000 (100mm) wafers per month.

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